SCES843A - JANUARY 2013-REVISED FEBRUARY 2013

16-BIT DUAL-SUPPLY BUS TRANSCEIVER WITH CONFIGURABLE VOLTAGE TRANSLATION AND 3-STATE OUTPUTS

Check for Samples: SN74LVC16T245-EP

FEATURES

- Control Inputs V_{IH} and V_{IL} Levels Are Referenced to V_{CCA} Voltage
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, Both Ports Are in the High-Impedance State
- Overvoltage-Tolerant Inputs and Outputs Allow Mixed-Voltage-Mode Data Communications
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

SUPPORTS DEFENSE, AEROSPACE, AND MEDICAL APPLICATIONS

- Controlled Baseline
- One Assembly and Test Site
- One Fabrication Site
- Available in Military (-55°C to 125°C)
 Temperature Ranges (1)
- Extended Product Life Cycle
- Extended Product-Change Notification
- Product Traceability
- (1) Custom temperature ranges available

DESCRIPTION

This 16-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

		$\overline{}$	$\overline{}$	
1DIR	[] 1	\cup	48	10E
1B1	2		47] 1A1
1B2	3		46] 1A2
GND	4		45	GND
1B3	5		44] 1A3
1B4	6		43] 1A4
V_{CCB}	7		42	VCCA
1B5	8		41] 1A5
1B6	9		40] 1A6
GND	[] 10		39	GND
1B7	11		38] 1A7
1B8	12		37] 1A8
2B1	13		36	2A1
2B2	[] 14		35	2A2
GND	[] 15		34	GND
2B3	16		33	2A3
2B4	[] 17		32	2A4
V_{CCB}	1 8		31	V _{CCA}
2B5	19		30	2A5
2B6	20		29	2A6
GND	21		28	GND
2B7	22		27	2A7
2B8	23		26	2A8
2DIR	24		25	2 <u>0E</u>

DGG PACKAGE

(TOP VIEW)



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DESCRIPTION (CONTINUED)

The SN74LVC16T245 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (\overline{OE}) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports always is active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ} .

The SN74LVC16T245 is designed so that the control pins (1DIR, 2DIR, $1\overline{OE}$, and $2\overline{OE}$) are supplied by V_{CCA} .

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, then both ports are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Table 1. ORDERING INFORMATION⁽¹⁾

T _A	PACKA	\GE	ORDERABLE PART NUMBER	TOP-SIDE MARKING	VID NUMBER
5500 to 40500	TCCOD DCC	Reel of 2000	CLVC16T245MDGGREP	LVCACTOAFN	V62/12667-01XE
–55°C to 125°C	TSSOP-DGG	Tube of 40	LVC16T245M		V62/12667-01XE-T

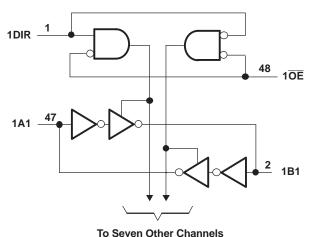
(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

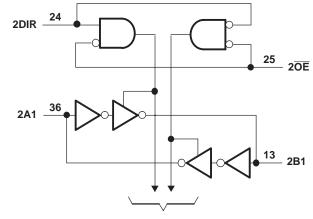
FUNCTION TABLE⁽¹⁾ (EACH 8-BIT SECTION)

CONTRO	L INPUTS	OUTPUT C	IRCUITS	OPERATION
ŌĒ	DIR	A PORT	B PORT	OPERATION
L	L	Enabled	Hi-Z	B data to A bus
L	Н	Hi-Z	Enabled	A data to B bus
Н	Χ	Hi-Z	Hi-Z	Isolation

(1) Input circuits of the data I/Os always are active.

LOGIC DIAGRAM (POSITIVE LOGIC)





To Seven Other Channels

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Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CCA}	Supply voltage range		-0.5	6.5	V
		I/O ports (A port)	-0.5	6.5	
V_{I}	Input voltage range ⁽²⁾	I/O ports (B port)	-0.5	6.5	V
		Control inputs	-0.5	6.5	
V	Voltage range applied to any output	A port	-0.5	6.5	V
Vo	in the high-impedance or power-off state (2)	B port	-0.5	6.5	V
V	Voltage range applied to any output in the high or law state (2) (3)	A port	-0.5	V _{CCA} + 0.5	V
Vo	Voltage range applied to any output in the high or low state (2) (3)	B port	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V _{CCA} , V _{CCB} , and GND			±100	mA
TJ	Maximum junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.

THERMAL INFORMATION

		SN74LVC16T245	
	THERMAL METRIC ⁽¹⁾	DGG	UNITS
		48 PINS	
θ_{JA}	Junction-to-ambient thermal resistance ⁽²⁾	59.9	
θ_{JCtop}	Junction-to-case (top) thermal resistance ⁽³⁾	13.9	
θ_{JB}	Junction-to-board thermal resistance (4)	27.1	90.00
ΨЈТ	Junction-to-top characterization parameter (5)	0.5	°C/W
ΨЈВ	Junction-to-board characterization parameter (6)	26.8	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance ⁽⁷⁾	N/A	

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.



Recommended Operating Conditions (1)(2)(3)(4)

			V _{CCI}	V _{CCO}	MIN	MAX	UNIT
V_{CCA}	0				1.65	5.5	
V _{CCB}	Supply voltage				1.65	5.5	V
	1		1.65 V to 1.95 V		V _{CCI} × 0.65		
	High-level	5 (5)	2.3 V to 2.7 V		1.7		.,
V_{IH}	input voltage	Data inputs ⁽⁵⁾	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		V _{CCI} × 0.7		
			1.65 V to 1.95 V			V _{CCI} × 0.35	
	Low-level	5 (5)	2.3 V to 2.7 V			0.7	.,
V _{IL}	input voltage	Data inputs ⁽⁵⁾	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			V _{CCI} × 0.3	
			1.65 V to 1.95 V		V _{CCA} × 0.65		
	High-level	Control inputs	2.3 V to 2.7 V		1.7		.,
V _{IH}	input voltage	(referenced to V _{CCA}) ⁽⁶⁾	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		V _{CCA} × 0.7		
			1.65 V to 1.95 V			V _{CCA} × 0.35	
	Low-level	Control inputs	2.3 V to 2.7 V			0.7	.,
V_{IL}	input voltage	(referenced to V _{CCA}) ⁽⁶⁾	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCA} \times 0.3$	
V _I	Input voltage	Control inputs			0	5.5	V
.,	lanut/output voltogo	Active state			0	V_{CCO}	V
V _{I/O}	Input/output voltage	3-State			0	5.5	V
				1.65 V to 1.95 V		-4	
	High-level output curr	rant		2.3 V to 2.7 V		-8	mA
ОН	nigri-level output curi	rent		3 V to 3.6 V		-24	IIIA
				4.5 V to 5.5 V		-32	
				1.65 V to 1.95 V		4	
ı	Low-level output curr	ont		2.3 V to 2.7 V		8	mA
OL	Low-level output curr	ent		3 V to 3.6 V		24	IIIA
				4.5 V to 5.5 V		32	
			1.65 V to 1.95 V			20	
Δt/Δv	Input transition	Data inputs	2.3 V to 2.7 V			20	ns/V
Δ(ΔV	rise or fall rate	Data Iliputs	3 V to 3.6 V			10	115/ V
<u></u>			4.5 V to 5.5 V			5	
T _A	Operating free-air ter	mperature			-55	125	°C

V_{CCI} is the V_{CC} associated with the input port.

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⁽²⁾

 V_{CCO} is the V_{CC} associated with the output port. All unused or driven (floating) data inputs (I/Os) of the device must be held at logic HIGH or LOW (preferably V_{CCI} or GND) to ensure proper device operation and minimize power. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

⁽⁴⁾ All unused data inputs of the device must be held at V_{CCA} or GND to ensure proper device operation.
(5) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V.
(6) For V_{CCA} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V.

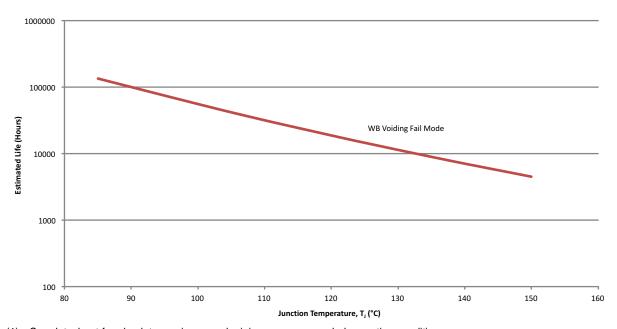
Electrical Characteristics (1)(2)

 $T_A = -55$ °C to 125°C, over recommended input voltage range (unless otherwise noted)

PAR	AMETER	TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	UNIT
		$I_{OH} = -100 \mu A$, $V_I = V_{IH}$	1.65 V to 4.5 V	1.65 V to 4.5 V	V _{CCO} - 0.1			
		$I_{OH} = -4 \text{ mA}, \qquad V_I = V_{IH}$	1.65 V	1.65 V	1.2			
V_{OH}		$I_{OH} = -8 \text{ mA}, \qquad V_I = V_{IH}$	2.3 V	2.3 V	1.9			V
		$I_{OH} = -24 \text{ mA}, \qquad V_I = V_{IH}$	3 V	3 V	2.35			
		$I_{OH} = -32 \text{ mA}, \qquad V_I = V_{IH}$	4.5 V	4.5 V	3.75			
		$I_{OL} = 100 \mu A, \qquad V_I = V_{IL}$	1.65 V to 4.5 V	1.65 V to 4.5 V			0.1	
		$I_{OL} = 4 \text{ mA}, \qquad V_I = V_{IL}$	1.65 V	1.65 V			0.45	
V_{OL}		$I_{OL} = 8 \text{ mA}, \qquad V_I = V_{IL}$	2.3 V	2.3 V			0.3	V
		$I_{OL} = 24 \text{ mA}, \qquad V_I = V_{IL}$	3 V	3 V			0.65	
		$I_{OL} = 32 \text{ mA}, \qquad V_I = V_{IL}$	4.5 V	4.5 V			0.65	
l _l	Control inputs	V _I = V _{CCA} or GND	1.65 V to 5.5 V	1.65 V to 5.5 V			±2	μΑ
	A or B	V V 0 to 5 5 V	0 V	0 to 5.5 V			±10	
off	port	V_I or $V_O = 0$ to 5.5 V	0 to 5.5 V	0 V			±10	μA
oz	A or B port	$\frac{V_O}{OE} = V_{CCO}$ or GND, $\frac{V_O}{OE} = V_{IH}$	1.65 V to 5.5 V	1.65 V to 5.5 V			±10	μΑ
			1.65 V to 5.5 V	1.65 V to 5.5 V			20	
CCA		$V_I = V_{CCI}$ or GND, $I_C = 0$	5 V	0 V			20	μΑ
		10 = 0	0 V	5 V			-2.5	
			1.65 V to 5.5 V	1.65 V to 5.5 V			20	
ССВ		$V_I = V_{CCI}$ or GND, $I_O = 0$	5 V	0 V			-2.5	μΑ
		10 – 3	0 V	5 V			20	
I _{CCA} + I ₀	ССВ	$V_I = V_{CCI}$ or GND, $I_O = 0$	1.65 V to 5.5 V	1.65 V to 5.5 V			30	μΑ
	A port	One A port at V _{CCA} - 0.6 V, DIR at V _{CCA} , B port = open					50	
∆I _{CCA}	DIR	DIR at $V_{CCA} - 0.6 \text{ V}$, B port = open, A port at V_{CCA} or GND	3 V to 5.5 V	3 V to 5.5 V			50	μA
ΔI _{CCB}	B port	One B port at V _{CCB} - 0.6 V, DIR at GND, A port = open	3 V to 5.5 V	3 V to 5.5 V			50	μΑ
Ci	Control inputs	V _I = V _{CCA} or GND	3.3 V	3.3 V		4		pF
C _{io}	A or B port	V _O = V _{CCA/B} or GND	3.3 V	3.3 V		8.5		pF

 $[\]begin{array}{ll} \hbox{(1)} & V_{CCO} \mbox{ is the } V_{CC} \mbox{ associated with the output port.} \\ \hbox{(2)} & V_{CCI} \mbox{ is the } V_{CC} \mbox{ associated with the input port.} \\ \end{array}$





(1) See datasheet for absolute maximum and minimum recommended operating conditions.

Figure 1. SN74LVC16T245-EP Operating Life Derating Chart

Switching Characteristics

 $T_A = -40$ °C to 85°C, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO (OUTPUT)	V _{CCB} = ± 0.1		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = ± 0.3		V _{CCB} = 5 V ± 0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α	В	1.7	21.9	1.3	9.2	1	7.4	0.8	7.1	ns
t _{PHL}	A	В	1.7	21.9	1.5	9.2	-	7.4	0.6	7.1	115
t _{PLH}	В	А	0.9	23.8	0.8	23.6	0.7	23.4	0.7	23.4	ns
t _{PHL}	В	A	0.9	23.0	0.6	23.0	0.7	23.4	0.7	23.4	115
t_{PHZ}	ŌĒ	А	1.6	29.6	1.5	29.4	1.5	29.3	1.4	29.2	ns
t_{PLZ}	OL	^	1.0	29.0	1.5	29.4	1.5	29.3	1.4	29.2	115
t_{PHZ}	ŌĒ	В	2.4	32.2	1.9	13.1	1.7	12	1.3	10.3	ns
t_{PLZ}	OE	Б	2.4	32.2	1.9	13.1	1.7	12	1.3	10.3	115
t _{PZH}	ŌĒ	А	0.4	24	0.4	23.8	0.4	23.7	0.4	23.7	ns
t _{PZL}	OE	^	0.4	24	0.4	23.0	0.4	23.1	0.4	23.1	115
t _{PZH}	ŌĒ	В	1.8	32	1.6	16	1.2	12.6	0.9	10.8	ns
t_{PZL}	OE	В	1.0	32	1.0	10	1.2	12.0	0.9	10.6	115

Switching Characteristics

 $T_A = -55$ °C to 125°C, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.8 V ± 0.15 V	V _{CCB} = 2.5 V ± 0.2 V	V _{CCB} = 3.3 V ± 0.3 V	V _{CCB} = 5 V ± 0.5 V	UNIT
	(INFO1)	(OUTFUT)	MIN MAX	MIN MAX	MIN MAX	MIN MAX	
t _{PLH}	A	В	25.9	13.2	11.4	11.1	ns
t _{PHL}	A	В	25.9	13.2	11.4	11.1	115
t _{PLH}	В	А	27.8	27.8	27.4	27.4	no
t _{PHL}	Б	A	21.0	21.0	21.4	27.4	ns
t _{PHZ}	ŌĒ	Α	33.6	33.4	33.3	33.2	ns
t_{PLZ}	OL	A	33.0	33.4	33.3	33.2	115
t_{PHZ}	ŌĒ	В	36.2	17.1	16	14.3	ns
t_{PLZ}	OL	В	30.2	17.1	10	14.3	115
t _{PZH}	ŌĒ	Α	28	27.8	27.7	27.7	ns
t_{PZL}	OE .	A	20	21.0	21.1	21.1	115
t _{PZH}	ŌĒ	В	36	22	16.6	14.8	ns
t_{PZL}	OE .	Б	30	22	10.0	14.0	115



Switching Characteristics

 $T_A = -40$ °C to 85°C, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO	V _{CCB} = ± 0.1		V _{CCB} = 2.5 V ± 0.2 V		V _{CCB} = 3.3 V ± 0.3 V		V _{CCB} = 5 V 0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	A	В	1.6	21.4	1.2	9	0.8	6.2	0.6	4.8	ns
t _{PHL}	A	Ь	1.0	21.4	1.2	9	0.0	0.2	0.0	4.0	115
t _{PLH}	В	Α	1.2	9.3	1	9.1	1	8.9	0.9	8.8	ns
t _{PHL}	В	Α	1.2	9.5		9.1		0.9	0.9	0.0	115
t_{PHZ}	 OE	Α	1.4	9	1.4	9	1.4	9	1.4	9	ns
t_{PLZ}	OL	Α	1.4	<u> </u>	1.4	9	1.4	3	1.4	3	113
t_{PHZ}	 OE	В	2.3	29.6	1.8	11	1.7	9.3	0.9	6.9	ns
t_{PLZ}	OL	Ь	2.5	23.0	1.0		1.7	9.0	0.5	0.9	113
t_{PZH}	OE	Α	1	10.9	1	10.9	1	10.9	1	10.9	ns
t_{PZL}	OE	Α	'	10.9	'	10.9	'	10.9	!	10.9	115
t_{PZH}	<u>OE</u>	В	1.7	28.2	1.6	12.9	1.2	9.4	1	6.9	ns
t_{PZL}	OL .	В	1.7	20.2	1.0	12.5	1.2	9.4	'	0.9	115

Switching Characteristics

 $T_A = -55$ °C to 125°C, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO (OUTPUT)	V _{CCB} = 1.8 V ± 0.15 V	V _{CCB} = 2.5 V ± 0.2 V	V _{CCB} = 3.3 V ± 0.3 V	V _{CCB} = 5 V 0.5 V	UNIT
	(INPUT)	(OUTPUT)	MIN MAX	MIN MAX	MIN MAX	MIN MAX	
t _{PLH}	Α	В	25.4	13	10.2	8.8	ns
t _{PHL}	^	Ь	20.4	13	10.2	0.0	113
t _{PLH}	В	Α	13.3	13.1	12.9	12.8	ns
t _{PHL}	ь	Α	13.3	13.1	12.9	12.0	115
t _{PHZ}	ŌĒ	Α	13	13	13	13	ns
t _{PLZ}	OL	Α	13	13	13	13	115
t _{PHZ}	ŌĒ	В	33.6	14	14.3	10.9	ns
t_{PLZ}	OL	В	33.0	14	14.5	10.9	115
t _{PZH}	ŌĒ	Α	14.9	14.9	14.9	14.9	ns
t _{PZL}	OE .	A	14.9	14.9	14.9	14.9	115
t _{PZH}	ŌĒ	В	32.2	16.9	13.4	10.9	ns
t _{PZL}	OE	В	32.2	16.9	13.4	10.9	115

Product Folder Links: SN74LVC16T245-EP

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Switching Characteristics

 $T_A = -40$ °C to 85°C, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO	V _{CCB} = ± 0.7	= 1.8 V 15 V		= 2.5 V 2 V	V _{CCB} = ± 0.3		V _{CCB} = 5 V ± 0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α	В	1.5	21.2	1.1	8.8	0.8	6.1	0.5	4.4	ns
t _{PHL}	Λ	Ь	1.5	21.2	1.1	0.0	0.0	0.1	0.5	4.4	113
t _{PLH}	В	Α	0.9	7.2	0.8	6.2	0.7	6.1	0.6	6	ns
t _{PHL}	В	^	0.9	1.2	0.0	0.2	0.7	0.1	0.0	O	115
t _{PHZ}	ŌĒ	Α	1.6	8.2	1.6	8.2	1.6	6.2	1.6	8.2	ns
t_{PLZ}	OL	Λ	1.0	0.2	1.0	0.2	1.0	0.2	1.0	0.2	115
t _{PHZ}	ŌĒ	В	2.1	29	1.7	10.3	1.5	8.6	0.8	6.3	ns
t_{PLZ}	OE	Б	2.1	29	1.7	10.3	1.5	0.0	0.6	0.3	115
t _{PZH}	ŌĒ	A	0.8	7.8	0.8	7.8	0.8	7.8	0.8	7.8	no
t _{PZL}		A	0.8	1.0	0.8	1.0	0.8	1.0	0.6	1.0	ns
t _{PZH}	ŌĒ	В	1.6	27.7	1.4	12.4	1.1	8.5	0.9	8.4	ns
t_{PZL}	OE	В	1.0	21.1	1.4	12.4	1.1	6.5	0.9	0.4	115

Switching Characteristics

 $T_A = -55$ °C to 125°C, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.8 V ± 0.15 V	V _{CCB} = 2.5 V ± 0.2 V	V _{CCB} = 3.3 V ± 0.3 V	V _{CCB} = 5 V ± 0.5 V	UNIT
	(INPUT)	(001701)	MIN MAX	MIN MAX	MIN MAX	MIN MAX	
t _{PLH}	А	В	25.2	12.8	10.2	8.4	ns
t _{PHL}	A	5	20.2	12.0	10.2	0.4	113
t _{PLH}	В	Α	11.2	10.2	10.1	10	ns
t _{PHL}	Ь	Α	11.2	10.2	10.1	10	115
t_{PHZ}	ŌĒ	А	12.2	12.2	12.2	12.2	ns
t _{PLZ}	OL		12.2	12.2	12.2	12.2	115
t_{PHZ}	ŌĒ	В	33	14.3	12.8	10.3	ns
t_{PLZ}	OE	Б	33	14.5	12.0	10.3	115
t _{PZH}	ŌĒ	^	11.8	12.1	12.1	10.1	20
t _{PZL}	OE	A	11.8	12.1	12.1	12.1	ns
t _{PZH}	ŌĒ	В	31.7	16.4	12.9	10.4	20
t _{PZL}	OE .	В	31.7	10.4	12.9	10.4	ns



Switching Characteristics

 $T_A = -40$ °C to 85°C, $V_{CCA} = 5$ V \pm 0.5 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO (OUTBUT)	V _{CC} = ± 0.1		V _{CC} = ± 0.2		V _{CC} = ± 0.3		V _{CC} = 5 V ± 0.5 V		UNIT		
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX			
t _{PLH}	A	В	1.6	21.4	1	8.8	0.7	6	0.4	4.2	ns		
t _{PHL}	Λ		1.0	21.4	'	0.0	0.7	U	0.4	4.2	113		
t _{PLH}	В	Α	0.7	6.8	0.4	4.8	0.3	4.5	0.3	4.3	ns		
t _{PHL}	В	A	0.7	0.0	0.4	4.0	0.5	4.5	0.5	4.5	115		
t _{PHZ}	ŌĒ	А	0.3	5.4	0.3	5.4	0.3	5.4	0.3	6.4	ns		
t _{PLZ}	OL		0.5	5.4	0.5	5.4	0.5	5.4	0.5	0.4	113		
t _{PHZ}	ŌĒ	В	2	28.7	1.6	9.7	1.4	8	0.7	5.7	ns		
t _{PLZ}	OL	<u>ل</u> ا	В	В		20.7	1.0	9.1	1.4	0	0.7	5.7	115
t _{PZH}	ŌĒ	Α	0.7	5.5	0.7	5.5	0.7	5.5	0.7	5.5	ns		
t _{PZL}	OE .	A	0.7	5.5	0.7	5.5	0.7	5.5	0.7	5.5	115		
t _{PZH}	OE	В	1.6	27.6	1.3	11.4	1	8.1	0.9	6	ns		
t _{PZL}	OL .	В	1.0	27.0	1.3	11.4		0.1	0.9	O	115		

Switching Characteristics

 $T_A = -55$ °C to 125°C, $V_{CCA} = 5 \text{ V} \pm 0.5 \text{ V}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V	$V_{CC} = 2.5 V$ $\pm 0.2 V$	$V_{CC} = 3.3 \text{ V} $ $\pm 0.3 \text{ V}$	V _{CC} = 5 V ± 0.5 V	UNIT
	(INPUT)	(OUTPUT)	MIN MAX	MIN MAX	MIN MAX	MIN MAX	
t _{PLH}	Α	В	25.4	14.3	10	8.2	ns
t _{PHL}		В	20.4	14.5	10	0.2	113
t _{PLH}	В	А	11	8.8	8.5	8.3	ns
t _{PHL}	ь	Α	11	0.0	6.5	0.3	115
t _{PHZ}	ŌĒ	А	9.4	9.4	9.4	9.4	ns
t _{PLZ}	OL	A	9.4	9.4	9.4	9.4	113
t _{PHZ}	ŌĒ	В	32.7	13.7	12	9.7	nc
t _{PLZ}	OL	В	32.7	13.7	12	9.7	ns
t _{PZH}	ŌĒ	Α	10.4	10.4	10.4	10.4	20
t _{PZL}	OE	A	10.4	10.4	10.4	10.4	ns
t _{PZH}	ŌĒ	В	31.6	19.3	12.6	10	20
t _{PZL}	OE .	В	31.0	19.3	12.0	10	ns

Operating Characteristics

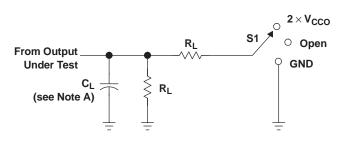
 $T_{\Delta} = 25^{\circ}C$

1 A - 20		TEST	V _{CCA} =	V _{CCA} =	V _{CCA} =	V _{CCA} =	
PARAMETER		CONDITIONS	V _{CCB} = 1.8 V TYP	V _{CCB} = 2.5 V TYP	V _{CCB} = 3.3 V TYP	V _{CCB} = 5 V	UNIT
C _{pdA} (1)	A-port input, B-port output		2	2	2	3	
C _{pd} A `	B-port input, A-port output	$C_L = 0$,	18	19	19	22	~ F
C _{pdB} (1)	A-port input, B-port output	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	18	19	20	22	pF
C _{pdB} ('')	B-port input, A-port output		2	2	2	2	

(1) Power dissipation capacitance per transceiver



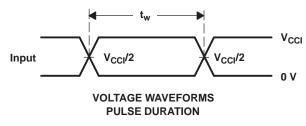
PARAMETER MEASUREMENT INFORMATION

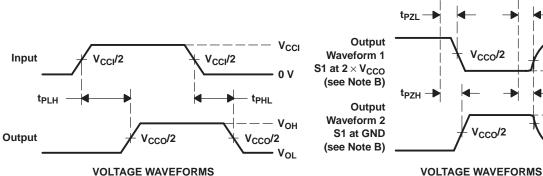


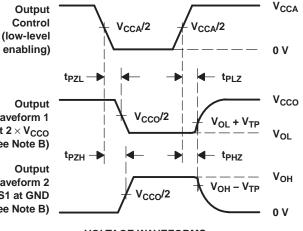
TEST	S 1
t _{pd}	Open
t _{PLZ} /t _{PZL}	$2 \times \mathbf{V_{CCO}}$
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

V _{CCO}	CL	R _L	V _{TP}
1.8 V \pm 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	15 pF	2 k Ω	0.15 V
3.3 V \pm 0.3 V	15 pF	2 k Ω	0.3 V
5 V ± 0.5 V	15 pF	2 k Ω	0.3 V







ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \le 10 \text{ MHz}$, $Z_O = 50 \Omega$, $dv/dt \ge 1 \text{ V/ns}$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.

PROPAGATION DELAY TIMES

J. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

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Product Folder Links: SN74LVC16T245-EP



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
CLVC16T245MDGGEP	ACTIVE	TSSOP	DGG	48	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LVC16T245M	Samples
CLVC16T245MDGGREP	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LVC16T245M	Samples
V62/12667-01XE	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LVC16T245M	Samples
V62/12667-01XE-T	ACTIVE	TSSOP	DGG	48	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	LVC16T245M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

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OTHER QUALIFIED VERSIONS OF SN74LVC16T245-EP:

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CLVC16T245MDGGREP	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1

www.ti.com 5-Jan-2022



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CLVC16T245MDGGREP	TSSOP	DGG	48	2000	367.0	367.0	45.0

PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

TUBE

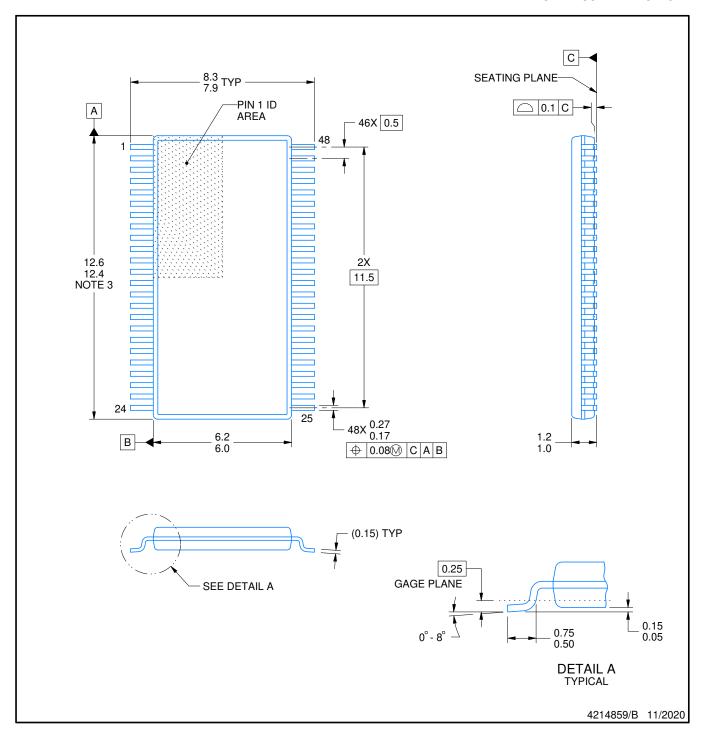


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CLVC16T245MDGGEP	DGG	TSSOP	48	40	530	11.89	3600	4.9
V62/12667-01XE-T	DGG	TSSOP	48	40	530	11.89	3600	4.9



SMALL OUTLINE PACKAGE



NOTES:

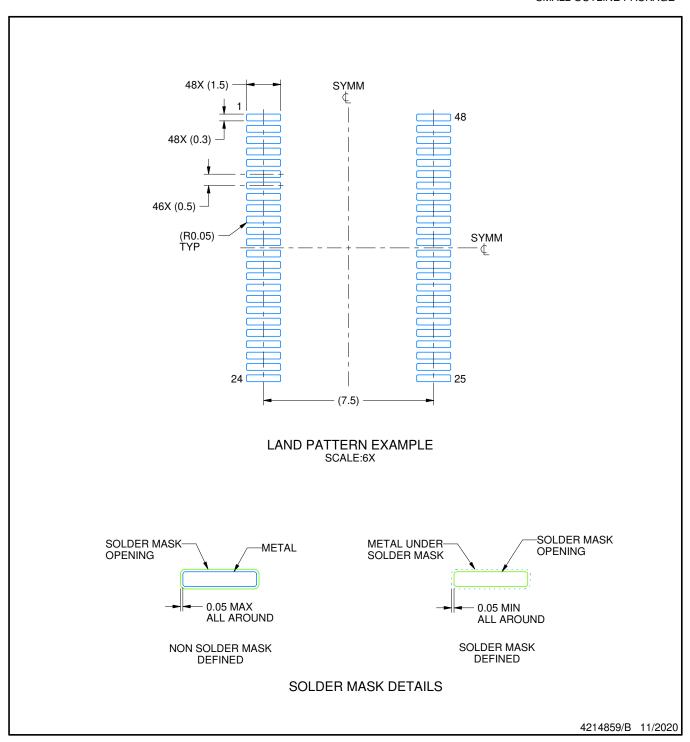
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

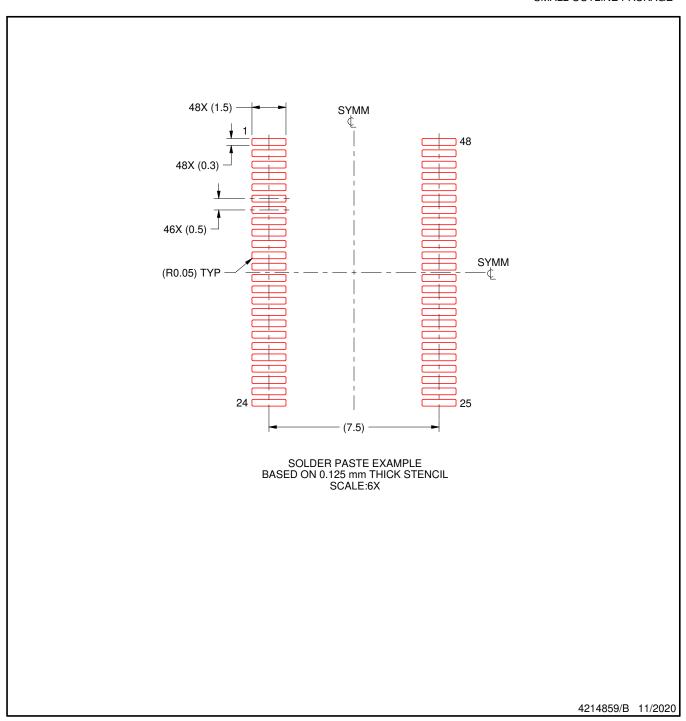


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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